SP814x Series 1.0pF 22KV Diode Array

HF RoHS Pb GREEN

OBSOLETE **DATE:** 06/10th/2020 **PCN/ECN#** ESU270-51
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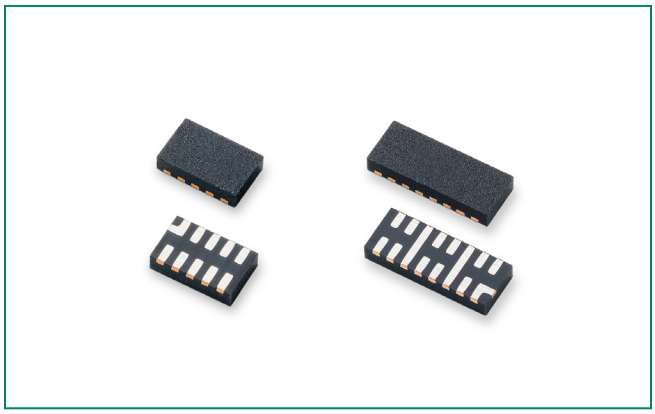
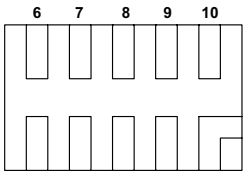


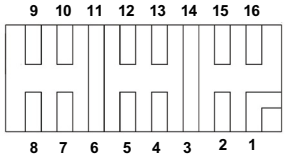
Description

The SP814x series integrates 4 or 6 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). This robust component can safely absorb repetitive ESD strikes above the maximum level specified in IEC 61000-4-2 international standard (±8kV contact discharge) without performance degradation. The extremely low loading capacitance also makes it ideal for protecting high speed signal pins such as HDMI2.0, USB3.0, USB2.0, and IEEE 1394.

Pinout



SP8142-04UTG

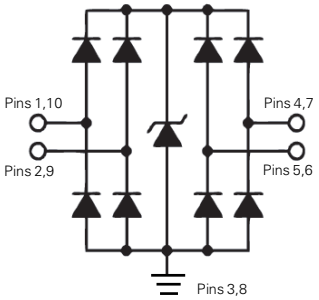


SP8143-06UTG

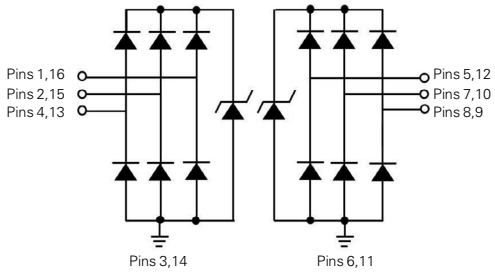
Features

- ESD, IEC 61000-4-2, ±22kV contact, ±22kV air
- EFT, IEC 61000-4-4, 40A (t_p=5/50ns)
- Lightning, IEC 61000-4-5 2nd edition,2.5A (t_p=8/20µs)
- Low capacitance of 1.0pF (TYP) per I/O
- Low leakage current of 25nA (TYP) at 5V
- Small form factor µDFN packages (JEDEC MO-229) saves board space
- AEC-Q101 qualified
- Moisture Sensitivity Level (MSL -1)
- Halogen free, lead free and RoHS compliant

Functional Block Diagram



SP8142-04UTG



SP8143-06UTG

Applications

- LCD/PDP TVs
- External Storage
- DVD/ Blue-Ray Players
- Desktops/Servers
- Notebooks/Tablets
- Set Top Boxes
- Mobile Phones
- Flash Memory Cards
- Digital Cameras

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current (t_p=8/20µs)	2.5	A
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Note: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

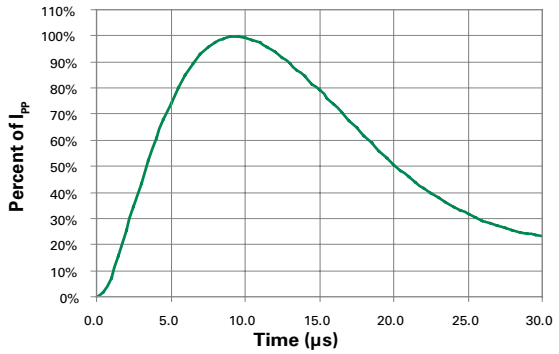
Electrical Characteristics (T_{OP}=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			5.0	V
Reverse Leakage Current	I_{LEAK}	V_R=5V, Any I/O to GND		25	50	nA
Channel Resistance	R_{CH}	Pins 1–10, 2–9, 4–7 and 5–6, SP8142 Pins 1–16, 2–15, 4–13 ,5–12, 7-10 and 8-9, SP8143		0.5		Ω
Clamp Voltage[1]	V_C	I_{PP}=1A, t_p=8/20µs, Fwd		9.2		V
		I_{PP}=2A, t_p=8/20µs, Fwd		10.3		V
Dynamic Resistance[2]	R_{DYN}	TLP, t_P=100ns, I/O to GND		0.3		Ω
ESD Withstand Voltage[1]	V_{ESD}	IEC 61000-4-2 (Contact)	±22			kV
		IEC 61000-4-2 (Air)	±22			kV
Diode Capacitance[1]	$C_{I/O-GND}$	Reverse Bias=0V, f=1 MHz		1.0		pF

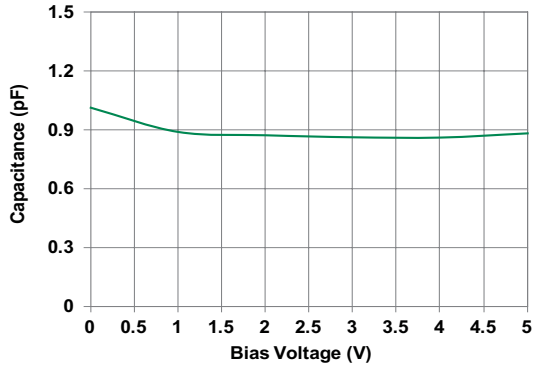
Note: [1] Parameter is guaranteed by design and/or component characterization.

[2] Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2= 90ns

8/20µs Pulse Waveform



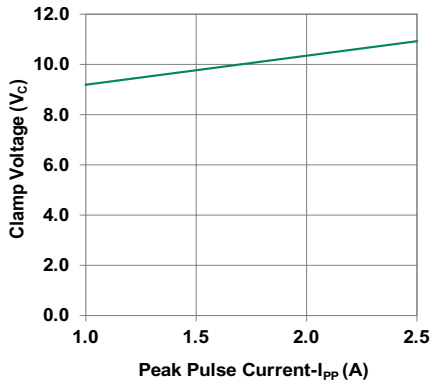
Capacitance vs. Reverse Bias



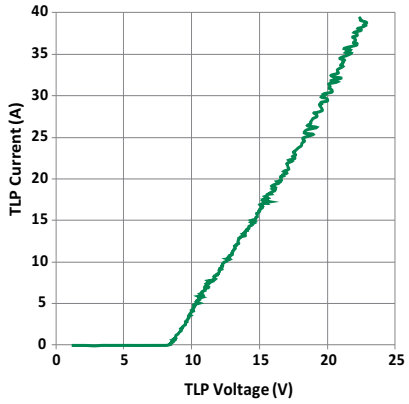
TVS Diode Arrays (SPA® Diodes)

Low Capacitance ESD Protection - SP814x Series

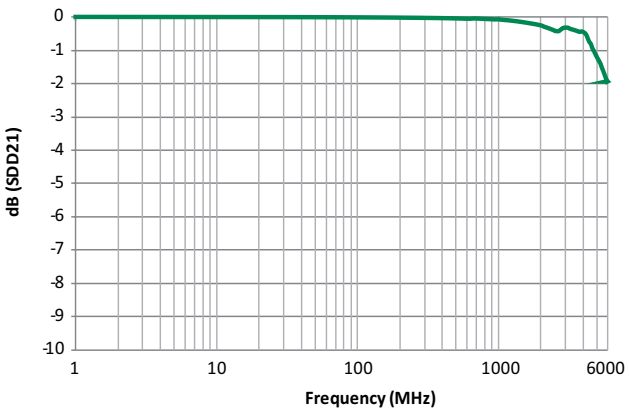
Clamping Voltage vs I_{PP}



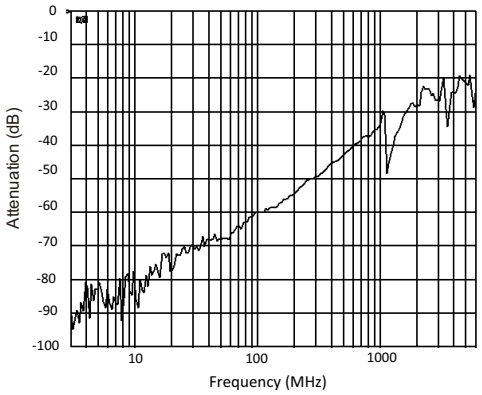
Transmission Line Pulsing(TLP) Plot



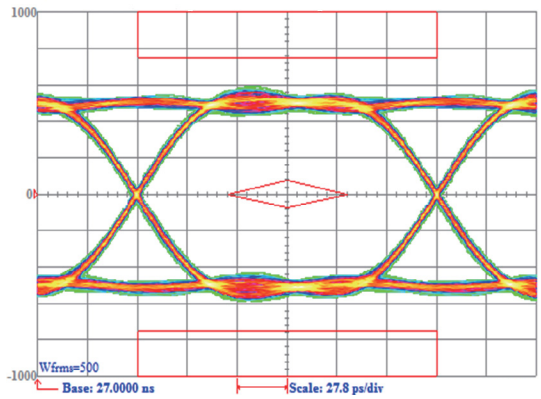
Differential Mode Attenuation SDD21 vs. Frequency



Analog Crosstalk (S41)



HDMI2.0 Eye Diagram



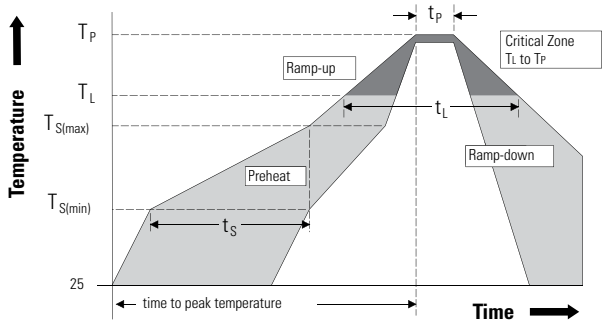
Revision: GD. 12/16/20

TVS Diode Arrays (SPA® Diodes)

Low Capacitance ESD Protection - SP814x Series

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	**- Temperature Min ($T_{s(min)}$)**	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	**- Temperature (T_L) (Liquidus)**	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		$260^{+0/-5}$ °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		260°C



Part Numbering System

SP 8142 - 04 U T G

- TVS Diode Arrays (SPA® Diodes)
- Series
- Number of Channels
  - -04=4 channels
  - -06=6 channels
- Package
  - U=µDFN-10 (2.2x1.35mm)
  - U=µDFN-16 (3.5x1.35mm)
- T= Tape & Reel
- G= Green

Part Marking System

Ⓒ H 4

- Product Series
  - Ⓒ= SP8142
  - Ⓓ= SP8143
- Assembly Site
- Number of Channels
  - 4=4 channels
  - 6=6 channels

Product Characteristics

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Substrate material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0.

Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.

Ordering Information

Part Number	Package	Marking	Min. Order Qty.
SP8142-04UTG	µDFN-10	ⒸH4	3000
SP8143-06UTG	µDFN-16	ⒹH6	3000

Revision: GD. 12/16/20

Application Information

Alternatives to Semiconductor-based Common Mode Filtering

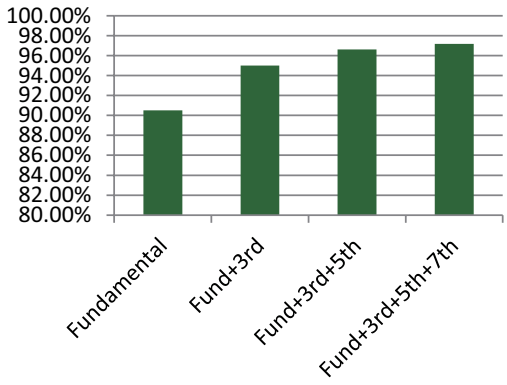
Conventional Semiconductor-based common mode filters' performance has been proven to be lacking. While excellent ESD components, the tradeoffs that designers encounter for signal integrity prove to be insurmountable.

Fundamentally, the common mode filters do not filter the unwanted signals (noise) fast enough, and create problems with resistive and inductive loading as signals pass through the components.

Odd harmonics add to signal strength, and create squarer waves, which are easier for the downstream components to detect either legal zero's or one's. Successive odd harmonics in the passband make the signal stronger. Noise generated from the fundamental frequencies does not get attenuated fast enough to meaningfully improve signal integrity, or lower the noise signature.

There are two options available (4 channel and 6 channel) and both are housed in leadless µDFN packages so the data lines can pass directly underneath the component to reduce discontinuities and maintain signal integrity.

Figure 1: Signal Strength of Fundamental



Signal Compression

Semiconductor-based components which this product are designed to replace have at least 6 ohms resistance, contributing to signal amplitude compression which negatively affect the eye height, and negatively affect Signal Integrity and compliance testing.

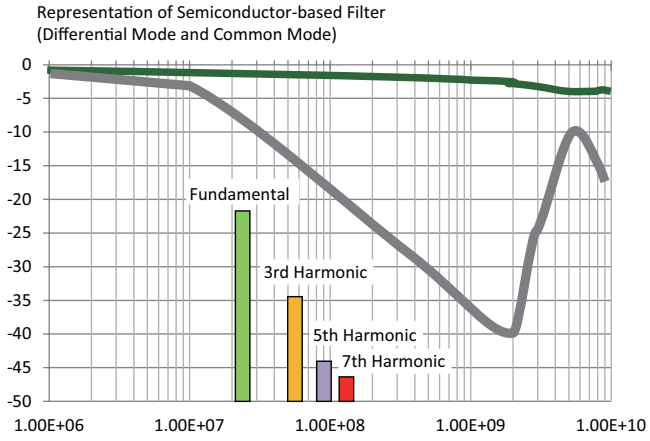
Alternatives to Semiconductor-based Common Mode Filtering

Using robust ESD protection, along with Signal Integrity best layout practices, including burying the high speed signals between two ground planes within the board permit excellent Signal Integrity, at a lower total solution cost. The SP8142/SP8143 are designed to be footprint compatible with existing solutions offering filtering, and can be used in the test scheme of testing without filtering (using SP8142/8143) and with filtering (other solutions) and comparing the results.

If the PCB layout is good, the engineer should expect to see higher levels of Signal Integrity and equal levels of radiated and conducted noise, at a lower pricepoint using the ESD only solutions.

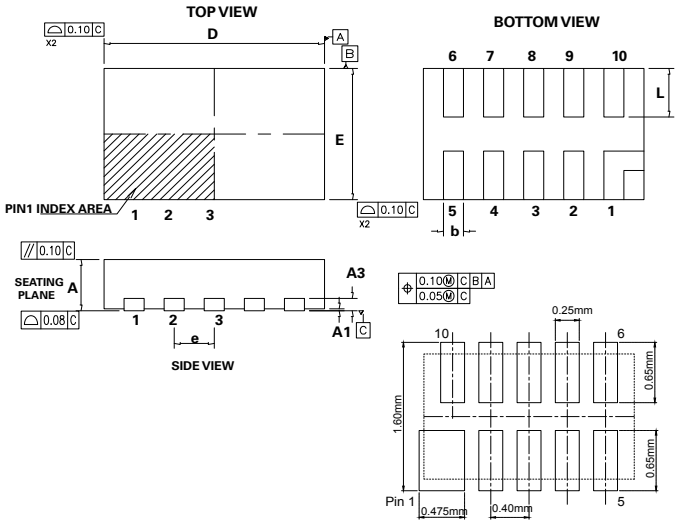
Figure 2: Typical multilayer PCB stack up, best to route data between ground planes to eliminate radiated noise and improve Signal Integrity.

Figure 3: Suppressing the odd harmonics off of the most popular interfaces



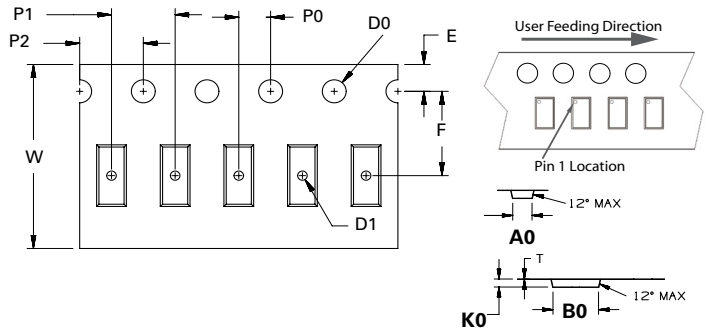
Interface	Fundamental	3rd Harmonic	3rd Harmonic Strength (% orig.)	5th Harmonic	5th Harmonic Strength (% orig.)
MIPI External	208 MHz	724 MHz	4.5%	1040 MHz	1.6%
HDMI 1.4a	248 MHz	744 MHz	4.5%	1240 MHz	1.6%
HDMI 2.0	600 MHz	1800 MHz	4.5%	3000 MHz	1.6%

Package Dimensions — µDFN-10

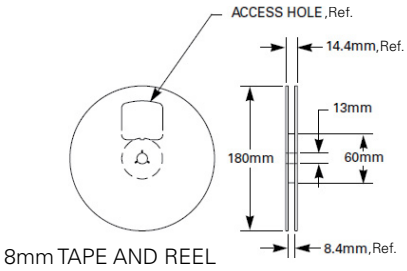


µDFN-10 (2.2x1.35)						
JEDEC MO-229						
Symbol	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	0.45	0.52	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
A3		0.127 Ref			0.005 Ref	
b	0.15	0.20	0.25	0.006	0.008	0.010
D	2.10	2.20	2.30	0.083	0.087	0.091
E	1.25	1.35	1.45	0.049	0.053	0.057
e		0.40 BSC			0.016 BSC	
L	0.40	0.50	0.60	0.016	0.020	0.024

Embossed Carrier Tape & Reel Specification — µDFN-10

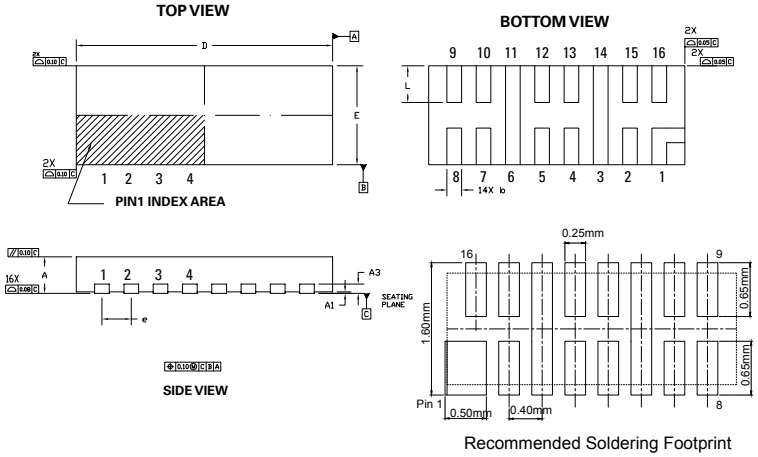


Symbol	Millimeters
A0	1.59 +/- 0.05
B0	2.45 +/- 0.05
D0	Ø1.50 + 0.10
D1	Ø 0.50 + 0.05
E	1.75 +/- 0.10
F	3.50 +/- 0.05
K0	0.69 +/- 0.05
P0	2.00 +/- 0.05
P1	4.00 +/- 0.10
P2	4.00 +/- 0.10
T	0.25 +/- 0.02
W	8.00 + 0.30 /- 0.10



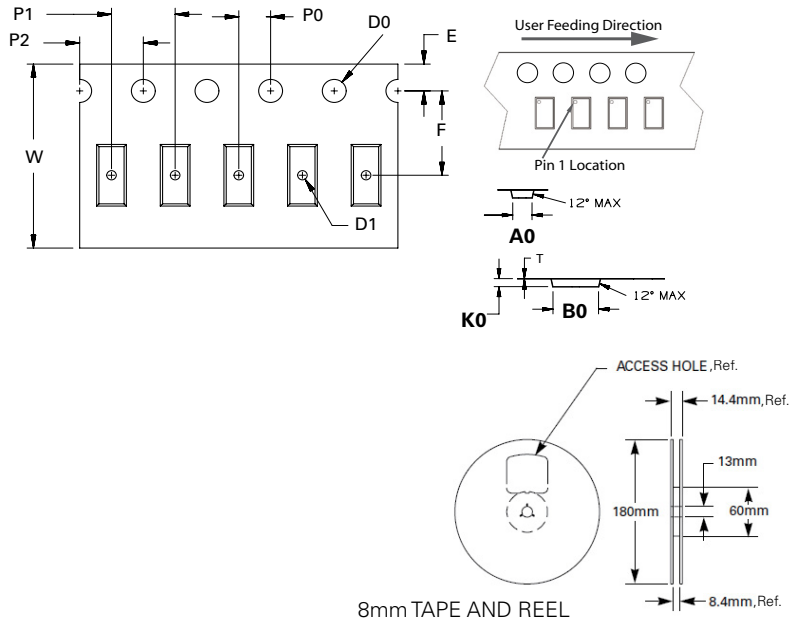
8mm TAPE AND REEL

Package Dimensions — µDFN-16



µDFN-16 (3.5x1.35mm)						
JEDEC MO-229						
Symbol	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	0.45	0.52	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
A3		0.127 Ref			0.005 Ref	
b	0.15	0.20	0.25	0.006	0.008	0.010
D	3.40	3.50	3.60	0.134	0.138	0.142
E	1.25	1.35	1.45	0.049	0.053	0.057
e		0.40 BSC			0.016 BSC	
L	0.40	0.50	0.60	0.016	0.020	0.024

Embossed Carrier Tape & Reel Specification — µDFN-16



Symbol	Millimeters
A0	1.58 +/- 0.10
B0	3.73 +/- 0.10
D0	Ø1.50 + 0.10
D1	Ø 0.60 + 0.05
E	1.75 +/- 0.10
F	5.50 +/- 0.05
K0	0.68 +/- 0.10
P0	2.00 +/- 0.05
P1	4.00 +/- 0.10
P2	4.00 +/- 0.10
T	0.28 +/- 0.02
W	12.00 + 0.30 /- 0.10